Green Products

SDUR3020WT ULTRAFAST PLASTIC RECTIFIER

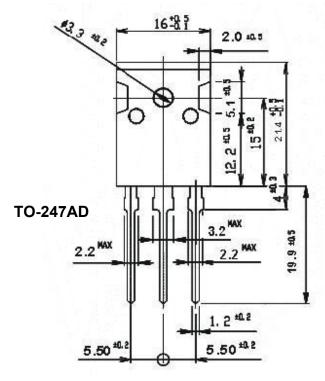
Applications:

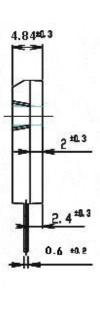
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

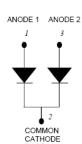
- Utra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm / Inches





TO-247AD



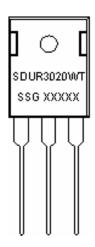
[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

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Marking Diagram:



Where XXXXX is YYWWL

SDUR = Device Type

30 = Forward Current (30A) 20 = Reverse Voltage (200V)

WT = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SDUR3020WT	TO-247AD (Pb-Free)	30pcs/ tube

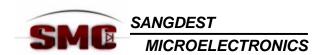
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	200	V
Average Rectified Forward Current	I _{F (AV)}	Rated Vr ,@Tc=140°C	30	А
Max. Peak One Cycle Non- Repetitive Surge Current (Per leg)	I _{FSM}	8.3ms, Half Sine pulse @ T _J = 25°C	110	Α

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Electrical Characteristics:

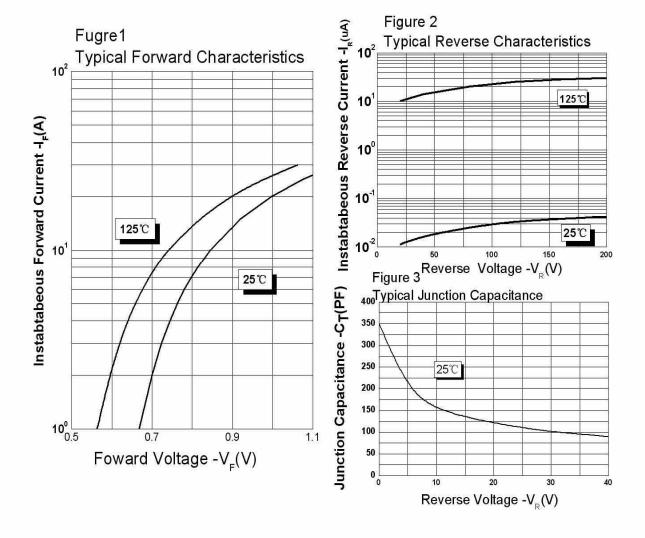
Characteristics	Symbol	Condition	MIN.	TYP.	Max.	Units
Breakdown voltage, Blocking voltage	V_{BR} V_{R}	I _R = 50μA	200	-	-	V
Max. Forward Voltage Drop*	V_{F1}	@ 15A, Pulse, T _J = 25°C	-	-	1.05	V
	V _{F2}	@ 15A, Pulse, T _J = 150°C	-	-	0.85	V
Max. Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	-	-	10	μΑ
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125^{\circ}C$	-	-	500	uA
Max. Reverse Recovery Time	t _{rr1}	I_F =500mA, I_R =1A,and I_m =250mA	-	-	35	ns

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	MIN.	TYP.	Max.	Units
Max. Junction Temperature	T_J	-	-65	-	150	°C
Max. Storage Temperature	T _{stg}	-	-65	-	150	°C
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	-	1.6	-	°C/W
Approximate Weight	wt	-	-	6.7	-	g
Case Style	TO-247AD					

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Technical Data
Data Sheet N0164 Rev. -

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